Voltage Regulator - Low Iq, Low Dropout, Power Good Output

1.2 A

NCP187

The NCP187 is 1.2 A LDO Linear Voltage Regulator. It is a very stable and accurate device with low quiescent current consumption (typ. 30 μA over the full temperature range), low dropout, low output noise and very good PSRR. The regulator incorporates several protection features such as Thermal Shutdown, Soft Start, Current Limiting and also Power Good Output signal for easy MCU interfacing.

Features

- Operating Input Voltage Range: 1.5 V to 5.5 V
- Adjustable and Fixed Voltage Options Available: 0.8 V to 5.2 V
- Low Quiescent Current: typ. 30 μA over Temperature
- ±2% Accuracy Over Full Load, Line and Temperature variations
- PSRR: 75 dB at 1 kHz
- Low Noise: typ. 15 μV_{RMS} from 10 Hz to 100 kHz
- Stable With Small 10 μF Ceramic Capacitor
- Soft−start to Reduce Inrush Current and Overshoots
- Thermal Shutdown and Current Limit Protection
- Power Good Signal Extends Application Range
- Available in WDFN6 and WDFNW6 2x2, 0.5P Packages
- This is Pb−free Device

Typical Applications

- Wireless Chargers
- Portable Equipment
- Smart Camera and Robotic Vision Systems
- Telecommunication and Networking Systems

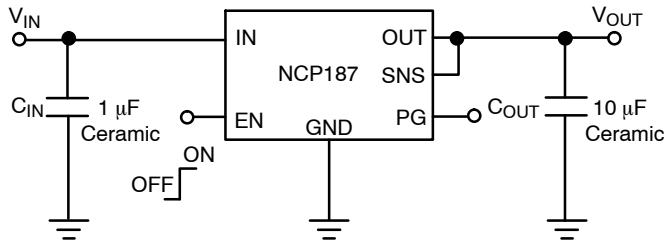
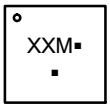


Figure 1. Typical Application Schematic

WDFN6/WDFNW6 2x2
CASES 511BR & 511DW

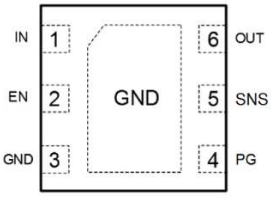
MARKING DIAGRAM



XX = Specific Device Code
M = Month Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



WDFN6, WDFNW6 2x2 mm
(Top View)

ORDERING INFORMATION

See detailed ordering and shipping information in on page 8 of this data sheet.

PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1	IN	Input pin. A small capacitor is needed from this pin to ground to assure stability
6	OUT	Regulated output voltage pin. A small 10 μF ceramic capacitor is needed from this pin to ground to assure stability
3, EXP	GND	Power supply ground
2	EN	Enable pin. Driving this pin high turns on the regulator. Driving EN pin low puts the regulator into shutdown mode
5	SNS	Sense pin. Connect this pin to regulated output voltage or resistor divider (adjustable version)
4	PG	Power Good, open collector. Use 10 kΩ to 100 kΩ pull−up resistor connected to output, input or other voltage (see maximum ratings)

ABSOLUTE MAXIMUM RATINGS

Ratings	Symbol	Value	Unit
Input Voltage (Note 1)	V_{IN}	−0.3 to 6	V
Enable Voltage	V_{EN}	−0.3 to 6	V
Power Good Current	I_{PG}	30	mA
Power Good Voltage	V_{PG}	−0.3 to 6	V
Output Voltage	V_{OUT}	−0.3 to V_{IN} + 0.3 (max. 5.5)	V
Output Short Circuit Duration	t_{SC}	Indefinite	s
Maximum Junction Temperature	$T_{J(MAX)}$	150	°C
Storage Temperature	T_{STG}	−55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD_{HBM}	2000	V
ESD Capability, Machine Model (Note 2)	ESD_{MM}	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTIS and APPLICATION INFORMATION for Safe Operating Area.
2. This device series incorporates ESD protection and is tested by the following methods:
   ESD Human Body Model tested per AEC−Q100−002 (EIA/JESD22−A114)
   ESD Machine Model tested per AEC−Q100−003 (EIA/JESD22−A115)
   Latch up Current Maximum Rating tested per JEDEC standard: JESD78

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
THERMAL CHARACTERISTICS, WDFN6, WDFNW6 2x2, 0.65 PITCH PACKAGE			
Thermal Resistance, Junction−to−Ambient (Note 3)	$R_{\theta JA}$	51	°C/W
Thermal Resistance, Junction−to−Case (top)	$R_{\theta JC(top)}$	142	°C/W
Thermal Resistance, Junction−to−Case (bottom) (Note 4)	$R_{\theta JC(bot)}$	7.8	°C/W
Thermal Resistance, Junction−to−Board	$R_{\theta JB}$	125	°C/W
Characterization Parameter, Junction−to−Top	Ψ_{JT}	2.0	°C/W
Characterization Parameter, Junction−to−Board	Ψ_{JB}	7.7	°C/W

3. The junction−to−ambient thermal resistance under natural convection is obtained in a simulation on a high−K board, following the JEDEC51.7 guidelines with assumptions as above, in an environment described in JESD51−2a.
4. The junction−to−case (bottom) thermal resistance is obtained by simulating a cold plate test on the IC exposed pad. Test description can be found in the ANSI SEMI standard G30−88.

ELECTRICAL CHARACTERISTICS ($-40°C \le T_J \le 125°C$; $VIN = V_{OUT}+1.0$ V; I_{OUT} = 10 mA, C_{IN} = 1 μF, C_{OUT} = 10 μF, unless otherwise noted. Typical values are at T_J = +25°C. (Note 6))

Parameter	Test Conditions		Symbol	Min	Typ	Max	Unit
Operating Input Voltage			V_{IN}	1.5		5.5	V
Output Voltage Accuracy	$-40°C \le T_J \le 125°C$, V_{OUT} +1 V < V_{IN} < 5.5 V, 0 mA < I_{OUT} < 1.2 A	V_{OUT} < 1.7 V	V_{OUT}	−35 mV		+35 mV	V
		$V_{OUT} \ge$ 1.7 V		−2 %		+2 %	
Reference Voltage			V_{REF}		0.8		V
Line Regulation	V_{OUT} + 1 V ≤ V_{IN} ≤ 5.5 V, I_{OUT} = 1 mA		Reg_{LINE}		40		μV/V
Load Regulation	I_{OUT} = 0 mA to 1.2 A		Reg_{LOAD}		2		μV/mA
Dropout voltage	$V_{DO} = V_{IN} - (V_{OUT(NOM)} - 3\%)$ I_{OUT} = 1.2 A	1.2 V – 1.4 V	V_{DO}		325	495	mV
		1.5 V – 1.7 V			240	400	
		1.8 V – 2.7 V			200	335	
		2.8 V – 3.2 V			165	250	
		3.3 V – 4.9 V			150	220	
		5 V			120	180	
Maximum Output Current	(Note 7)		I_{OUT}	1300	1750		mA
Short Circuit Current	(Note 7)		I_{SC}		1850		mA
Disable Current	V_{EN} = 0 V		I_{DIS}		0.1	5.0	μA
Quiescent Current	I_{OUT} = 0 mA		I_Q		30	45	μA
Ground current	I_{OUT} = 1.2 A		I_{GND}		2		mA
Power Supply Rejection Ratio	V_{IN} = 3.5 V + 100 mVpp V_{OUT} = 2.5 V I_{OUT} = 10 mA, C_{OUT} = 1 μF	f = 1 kHz	PSRR		75		dB
Output Noise Voltage	VOUT = 1.8 V, IOUT = 10 mA f = 10 Hz to 100 kHz		V_N		15		μV_{rms}
Enable Input Threshold Voltage	Voltage increasing		V_{EN_HI}	0.9	–	–	V
	Voltage decreasing		V_{EN_LO}	–	–	0.3	
EN Pin Current	V_{EN} = 5.5 V				100		nA
Active Output Discharge Resistance	V_{IN} = 5.5 V, V_{EN} = 0 V		R_{DIS}		120		Ω
Power Good, Output Voltage Raising			V_{PGup}		92		%
Power Good, Output Voltage Falling			V_{PGdw}		80		%
Power Good Output Voltage Low	I_{PG} = 6 mA, Open drain		V_{PGlo}		0.14	0.4	V
Thermal Shutdown Temperature (Note 5)	Temperature increasing from T_J = +25°C		T_{SD}		170		°C
Thermal Shutdown Hysteresis (Note 5)	Temperature falling from TSD		T_{SDH}	–	15	–	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Guaranteed by design and characterization.
6. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at $T_J = T_A$ = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
7. Respect SOA.

TYPICAL CHARACTERISTICS

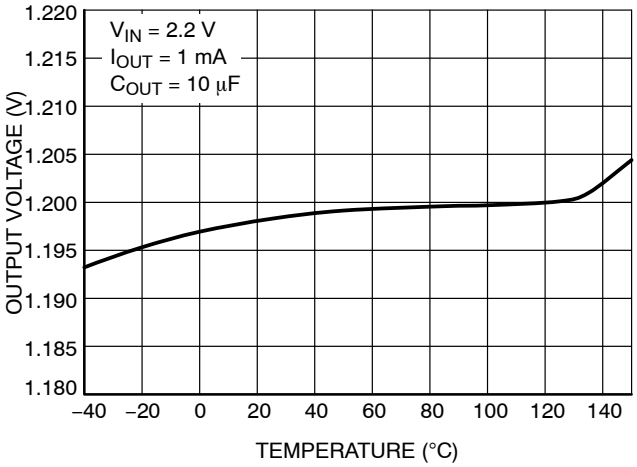


Figure 2. Output Voltage vs. Temperature – V_{OUT} = 1.2 V

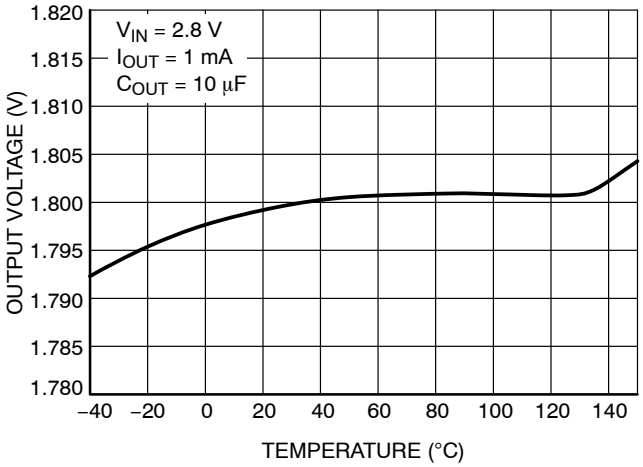


Figure 3. Output Voltage vs. Temperature – V_{OUT} = 1.8 V

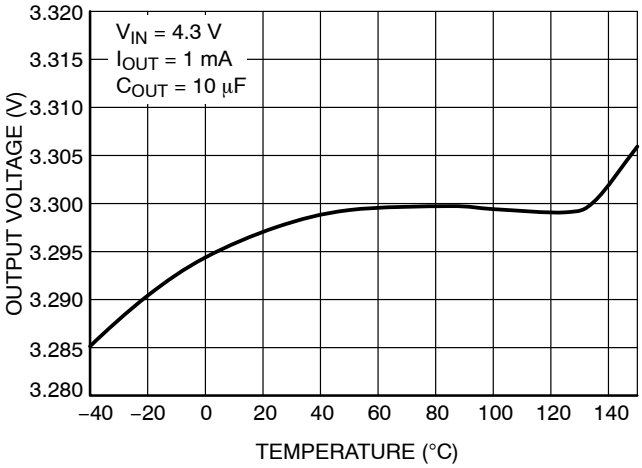


Figure 4. Output Voltage vs. Temperature – V_{OUT} = 3.3 V

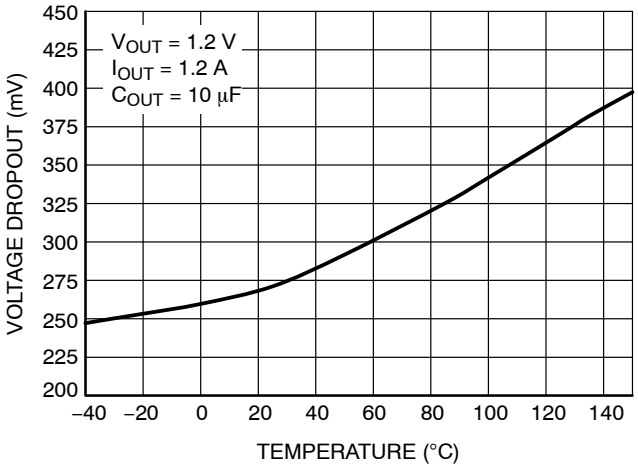


Figure 5. Dropout Voltage vs. Temperature – V_{OUT} = 1.2 V

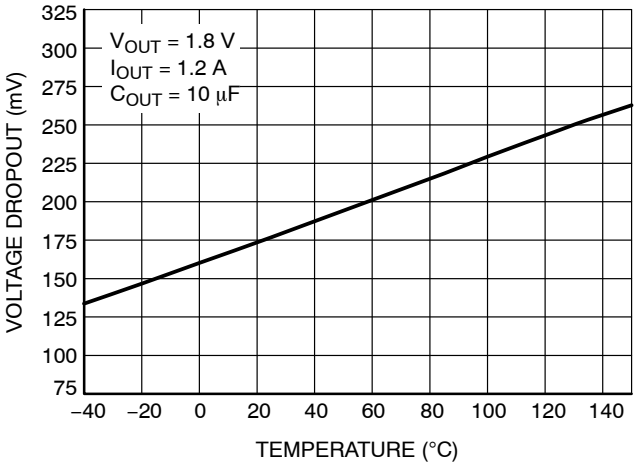


Figure 6. Dropout Voltage vs. Temperature – V_{OUT} = 1.8 V

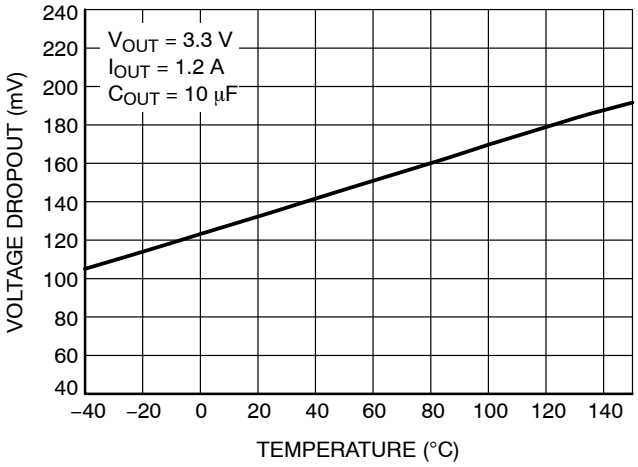


Figure 7. Dropout Voltage vs. Temperature – V_{OUT} = 3.3 V

TYPICAL CHARACTERISTICS

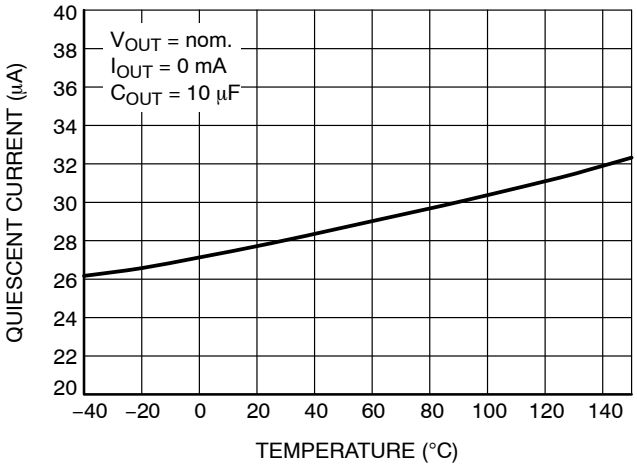


Figure 8. Quiescent Current vs. Temperature

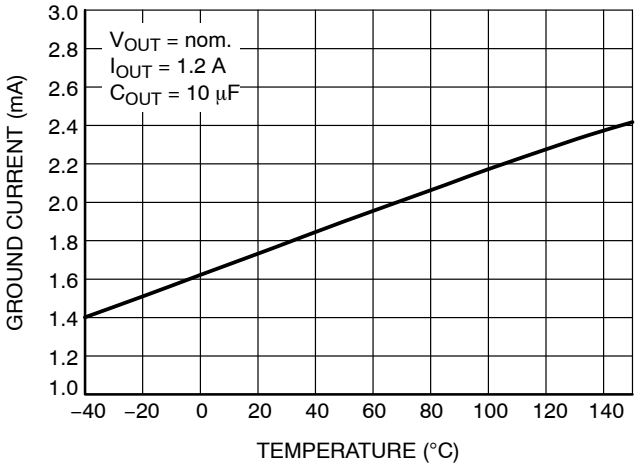


Figure 9. Ground Current vs. Temperature

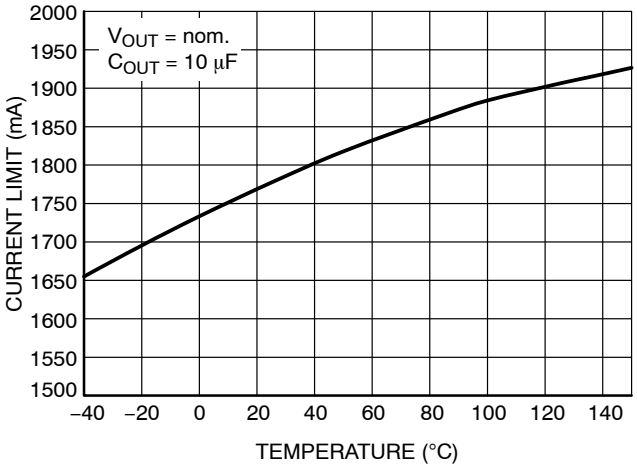


Figure 10. Current Limit vs. Temperature

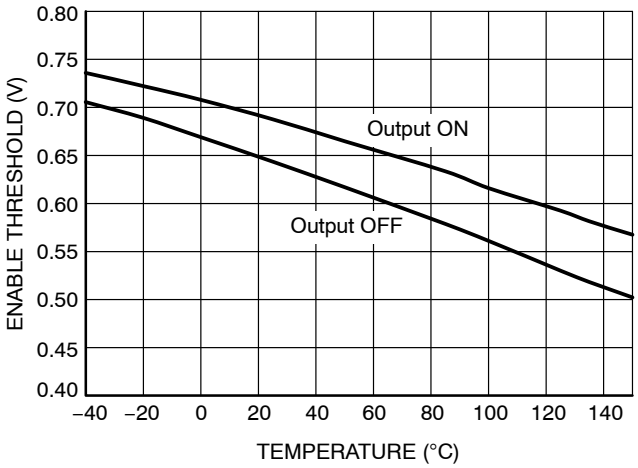


Figure 11. Enable Thresholds vs. Temperature

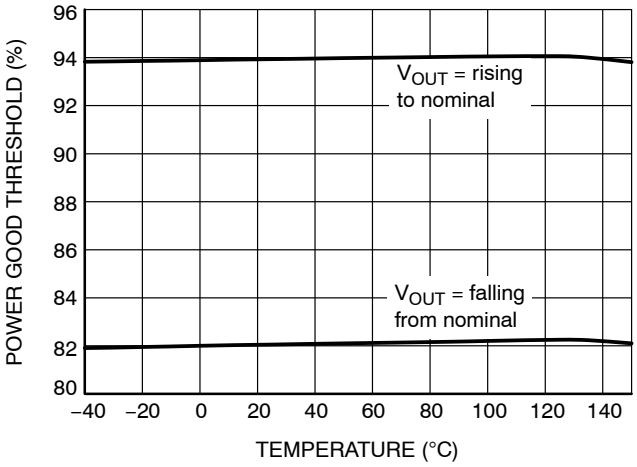


Figure 12. Power Good Thresholds vs. Temperature

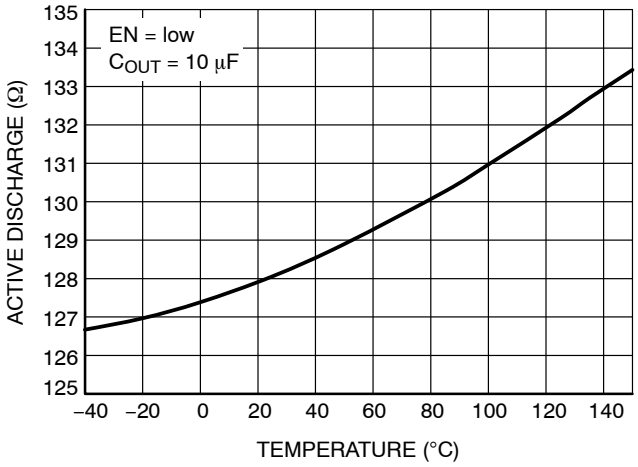


Figure 13. Active Discharge Resistance vs. Temperature

TYPICAL CHARACTERISTICS

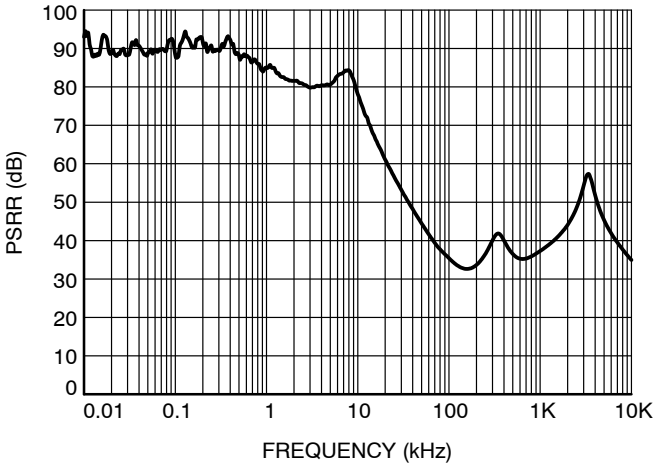


Figure 14. Power Supply Rejection Ratio for V_{OUT} = 1.8 V, I_{OUT} = 10 mA, C_{OUT} = 10 μF

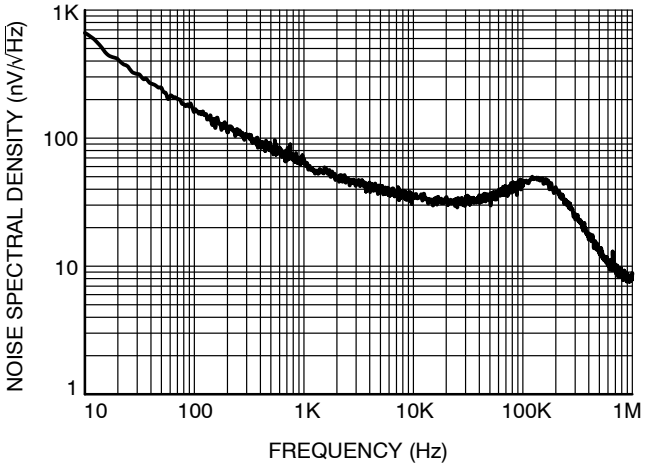


Figure 15. Output Voltage Noise Spectral Density for V_{OUT} = 1.8 V, I_{OUT} = 10 mA, C_{OUT} = 10 μF

APPLICATIONS INFORMATION

The NCP187 is the member of new family of high output current and low dropout regulators which delivers low quiescent and ground current consumption, good noise and power supply ripple rejection ratio performance. The NCP187 incorporates EN pin and power good output for simple controlling by MCU or logic. Standard features include current limiting, soft−start feature and thermal protection.

Input Decoupling (C_{IN})

It is recommended to connect at least 1 μF ceramic X5R or X7R capacitor between IN and GND pin of the device. This capacitor will provide a low impedance path for any unwanted AC signals or noise superimposed onto constant input voltage. The good input capacitor will limit the influence of input trace inductances and source resistance during sudden load current changes. Higher capacitance and lower ESR capacitors will improve the overall line transient response.

Output Decoupling (C_{OUT})

The NCP187 does not require a minimum Equivalent Series Resistance (ESR) for the output capacitor. The device is designed to be stable with standard ceramics capacitors with values of 4.7 μF or greater. Recommended capacitor for the best performance is 10 μF. The X5R and X7R types have the lowest capacitance variations over temperature thus they are recommended.

Power Good Output Connection

The NCP187 include Power Good functionality for better interfacing to MCU system. Power Good output is open collector type, capable to sink up to 10 mA. Recommended operating current is between 10 μA and 1 mA to obtain low saturation voltage. External pull−up resistor can be connected to any voltage up to 5.5 V (please see Absolute Maximum Ratings table above). Please note that Power Good internal circuitry is non−functional (disabled) to achieve the lowest possible internal current consumption in case of disabled LDO through Enable input (EN = Low). In this case internal Power Good transistor is open and output logic level is defined by voltage used for pull−up resistor. When Power Good is intended to be used as part of power sequencing functionality, then please connect external pull−up resistor to output voltage of NCP187. This will allow you to get correct low PG signal when LDO is disabled. Active discharge option is recommended to discharge output capacitors connected to LDO.

Power Good signal is internally delayed avoiding reaction to short glitches in output voltage. Blanking time is about 7 μs when voltage is decreasing from nominal value and about 15 μs when voltage is increasing back to nominal value.

Power Dissipation and Heat Sinking

The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. For reliable operation junction temperature should be limited to +125°C. The maximum power dissipation the NCP187 can handle is given by:

$$P_{D(MAX)} = \frac{\left[T_{J(MAX)} - T_A\right]}{R_{\theta JA}} \qquad \text{(eq. 1)}$$

The power dissipated by the NCP187 for given application conditions can be calculated from the following equations:

$$P_D \approx V_{IN}\left(I_{GND}(I_{OUT})\right) + I_{OUT}\left(V_{IN} - V_{OUT}\right) \quad \text{(eq. 2)}$$

or

$$V_{IN(MAX)} \approx \frac{P_{D(MAX)} + \left(V_{OUT} \times I_{OUT}\right)}{I_{OUT} + I_{GND}} \quad \text{(eq. 3)}$$

Hints

VIN and GND printed circuit board traces should be as wide as possible. When the impedance of these traces is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the NCP187, and make traces as short as possible.

ADJUSTABLE VERSION

Not only adjustable version, but also any fixed version can be used to create adjustable voltage, where original fixed voltage becomes reference voltage for resistor divider and feedback loop. Output voltage can be equal or higher than original fixed option, while possible range is from 0.8 V up to 5.2 V. Picture below shows how to add external resistors to increase output voltage above fixed value.

Output voltage is then given by equation:

$$V_{OUT} = V_{FIX} \times (1 + R1/R2)$$

where V_{FIX} is voltage of original fixed version (from 0.8 V up to 5.2 V). Do not operate the device at output voltage about 5.2 V, as device can be damaged.

In order to avoid influence of current flowing into SNS pin to output voltage accuracy (SNS current varies with voltage option and temperature, typical value is 300 nA) it is recommended to use values of R1 and R2 below 500 kΩ.

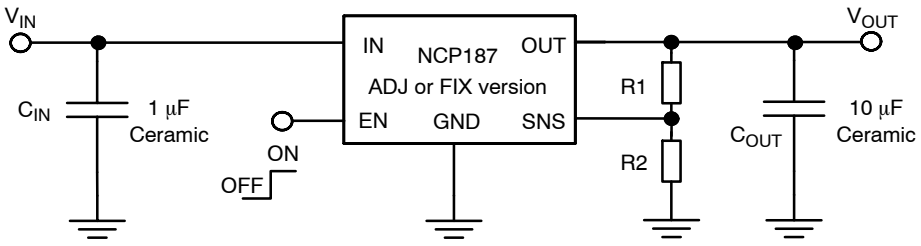


Figure 16.

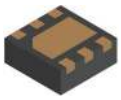
Please note that output noise is amplified by V_{OUT} / V_{FIX} ratio. For example, if original 0.8 V fixed variant is used to create 3.6 V output voltage, output noise is increased 3.6/0.8 = 4.5 times and real value will be 4.5 × 15 μV_{rms} = 67.5 μV_{rms}. For noise sensitive applications it is recommended to use as high fixed variant as possible – for example in case above it is better to use 3.3 V fixed variant to create 3.6 V output voltage, as output noise will be amplified only 3.6/3.3 = 1.09 × (16.4 μV_{rms}).

ORDERING INFORMATION

Device part no.	Voltage Option	Marking	Option	Package	Shipping†
NCP187AMTADJTAG	ADJ.	TA	With Active Output Discharge	WDFN6 2x2 non WF (Pb−Free)	3000 / Tape & Reel
NCP187AMT080TAG	0.8V	TC			
NCP187AMT120TAG	1.2V	TJ			
NCP187AMT330TAG	3.3V	TL			
NCP187AMTWADJTAG	ADJ.	L2	With Active Output Discharge	WDFNW6 2x2 WF SLP (Pb−Free)	
NCP187AMTW080TAG	0.8V	LG			

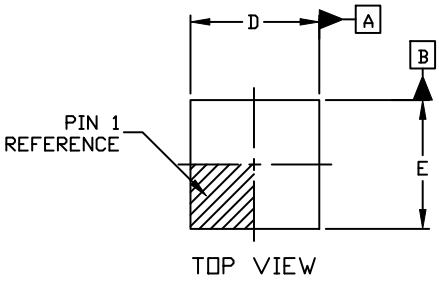
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

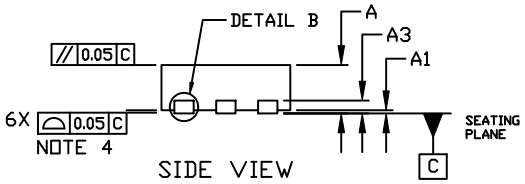
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

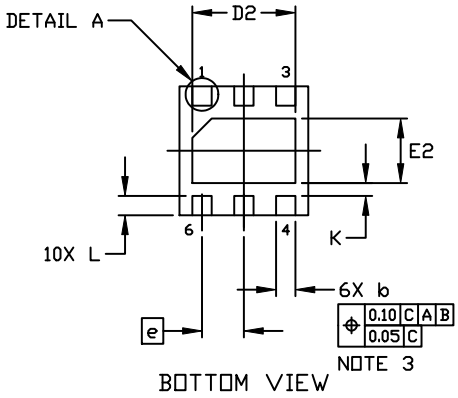


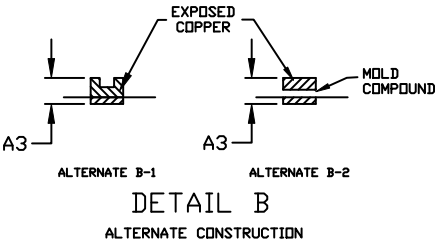
WDFN6 2x2, 0.65P
CASE 511BR
ISSUE C

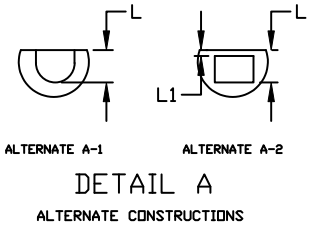
DATE 01 DEC 2021





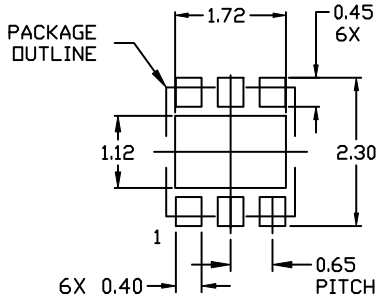






NOTES:
1. DIMENSION AND TOLERANCING PER ASME Y14.5, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM THE TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.70	0.75	0.80
A1	0.00	---	0.05
A3		0.20 REF	
b	0.25	0.30	0.35
D	1.90	2.00	2.10
D2	1.50	1.60	1.70
E	1.90	2.00	2.10
E2	0.90	1.00	1.10
e		0.65 BSC	
K		0.20 REF	
L	0.20	0.30	0.40
L1	---	---	0.15



For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*

XX = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	**98AON55829E**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.
DESCRIPTION:	**WDFN6 2X2, 0.65P**	**PAGE 1 OF 1**

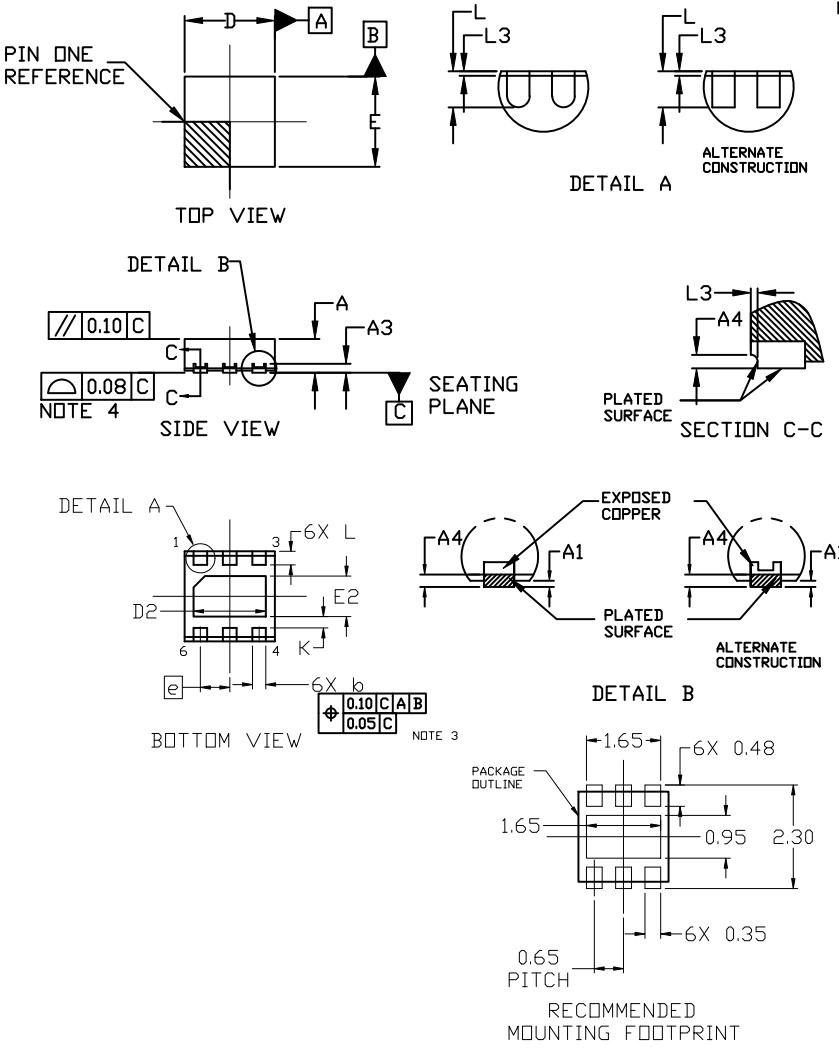
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

ON Semiconductor®

WDFNW6 2x2, 0.65P
CASE 511DW
ISSUE B

DATE 15 JUN 2018

SCALE 4:1

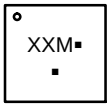


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b APPLIES TO PLATED TERMINALS AND IS MEASURED BETWEEN 0.15 AND 0.30MM FROM THE TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. THIS DEVICE CONTAINS WETTABLE FLANK DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.

	MILLIMETERS		
DIM	MIN.	NOM.	MAX.
A	0.70	0.75	0.80
A1	---	---	0.05
A3	0.20 REF		
A4	0.10	---	---
b	0.25	0.30	0.35
D	1.90	2.00	2.10
D2	1.50	1.60	1.70
E	1.90	2.00	2.10
E2	0.80	0.90	1.00
e	0.65 BSC		
K	0.25 REF		
L	0.25	0.30	0.35
L3	0.05 REF		

GENERIC MARKING DIAGRAM*



M = Month Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**WDFNW6 2x2, 0.65P**		**PAGE 1 OF 1**

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